Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:

Glass

Overall Length:

0.300 inches

Terminal Length:

1.000 inches

Overall Diameter:

0.130 inches

Mounting Method:

Terminal

Features Provided:

Hermetically sealed case

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

3.3 regulator voltage

Current Rating Per Characteristic:

116.00 milliamperes repetitive peak forward current

Power Rating Per Characteristic:

400.0 milliwatts small-signal input power, common-collector preset

Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

Special Features:

Gnuclear hardness critical item; no drawing to determine if isc code 1 item should also be nuclear hardness. Can't change criticality code to reflect nuclear hardness; junction pattern arrangement: pin

Precious Material And Location:

Leads gold

Precious Material:

Gold

Test Data Document:

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

Terminal Type And Quantity:

2 uninsulated wire lead

Specification Data:

81349-mil-s-19500/435 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig: